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FQB27N25TM F085/FQI27N25TU F085

May 2014

# **N-Channel MOSFET**

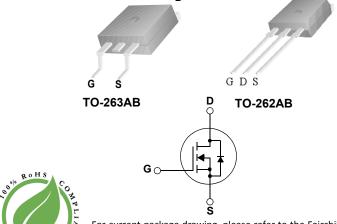
250 V, 25.5 A, 131 mΩ

### **Features**

- Typ  $R_{DS(on)}$  = 108m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 25.5A
- Typ  $Q_{q(tot)}$  = 45nC at  $V_{GS}$  = 10V,  $I_D$  = 27A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

### **Applications**

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems



For current package drawing, please refer to the Fairchild website at www.fairchildsemi.com/packaging

# MOSFET Maximum Ratings T<sub>.1</sub> = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage		250	V
V <sub>GS</sub>	Gate to Source Voltage		±30	V
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> = 25°C	25.5	^
I <sub>D</sub>	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	972	mJ
Г	Power Dissipation		417	W
$P_D$	Derate above 25°C		3.3	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 150	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.3	°C/W
R <sub>0.IA</sub>	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W

## **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FQB27N25TM	FQB27N25TM_F085	TO-263AB	330mm	24mm	800 units
FQI27N25TU	FQI27N25TU_F085	TO-262AB	Tube	N/A	50 units

- 1: Current is limited by bondwire configuration.
- Starting T<sub>J</sub> = 25°C, L = 4.67mH, I<sub>AS</sub> = 20.4A, V<sub>DD</sub> = 100V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche.
   R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design while R<sub>θJA</sub> is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Units

Max.

Тур.

# **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted.

**Parameter** 

Off Characteristics								
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, \	/ <sub>GS</sub> = 0V	250	-	-	V	
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>DS</sub> =250V,	$T_{\rm J} = 25^{\rm o}{\rm C}$	-	-	1	μΑ	
		$V_{GS} = 0V$	$T_J = 150^{\circ}C(Note 4)$	-	-	250	uA	
less	Gate to Source Leakage Current	$V_{GS} = \pm 30V$		-	_	±100	nA	

**Test Conditions** 

Min.

## On Characteristics

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		3.0	4.1	5.0	V
P. Drain to Source On Registance	Drain to Source On Resistance	I <sub>D</sub> = 25.5A,	$T_{\rm J} = 25^{\rm o}{\rm C}$	-	108	131	$m\Omega$
CDS(on)	R <sub>DS(on)</sub> Drain to Source On Resistance	V <sub>GS</sub> = 10V	$T_J = 150^{\circ}C(Note 4)$	-	265	310	mΩ

# **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 05V V 0V		-	1800	-	pF
C <sub>oss</sub>	Output Capacitance	→ v <sub>DS</sub> = 25v, v <sub>GS</sub> = 1 — f = 1MHz	$V_{DS} = 25V, V_{GS} = 0V,$		350	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	-1 = 11VID2		-	45	-	pF
$R_g$	Gate Resistance	f = 1MHz		-	0.82	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V	V <sub>DD</sub> = 125V	-	45	49	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$	I <sub>D</sub> = 27A	-	3.3	4	nC
$Q_{gs}$	Gate to Source Gate Charge			-	12	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge			-	23	-	nC

# **Switching Characteristics**

t <sub>on</sub>	Turn-On Time		-	-	196	ns
t <sub>d(on)</sub>	Turn-On Delay		-	36	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 125V, I <sub>D</sub> = 27A,	-	122	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	$V_{GS}$ = 10V, $R_{GEN}$ = 25 $\Omega$	-	81	-	ns
t <sub>f</sub>	Fall Time		-	60	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	164	ns

## **Drain-Source Diode Characteristics**

V	Source to Drain Diode Voltage	$I_{SD}$ = 25.5A, $V_{GS}$ = 0V	-	-	1.5	V
$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 12.75A, V_{GS} = 0V$	-	-	1.25	V
t <sub>rr</sub>	ReverseRecovery Time	$I_F = 27A$ , $dI_{SD}/dt = 100A/\mu s$ ,	-	205	238	ns
Q <sub>rr</sub>	ReverseRecovery Charge	V <sub>DD</sub> =200V	-	1.8	2.3	nC

#### Notes

4: The maximum value is specified by design at  $T_J$  = 150°C. Product is not tested to this condition in production.

# **Typical Characteristics**

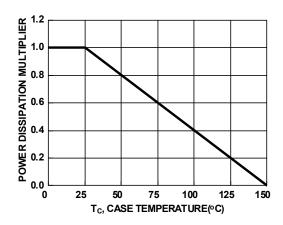
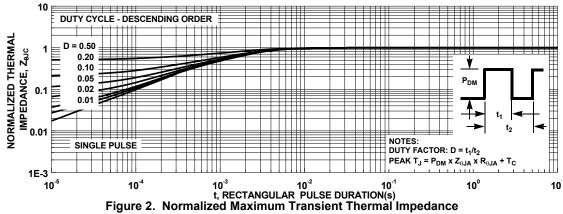


Figure 1. Normalized Power Dissipation vs. Case **Temperature** 





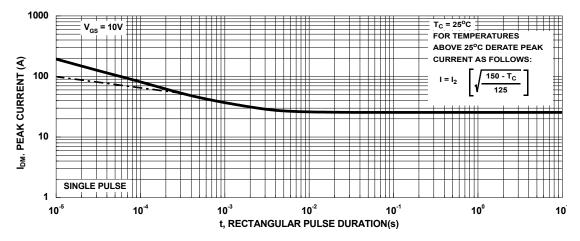


Figure 3. Peak Current Capability

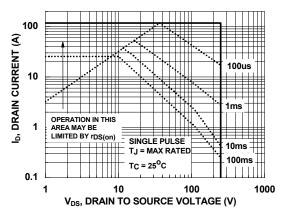
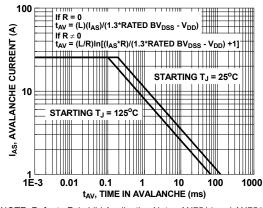


Figure 4. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 5. Unclamped Inductive Switching

Capability

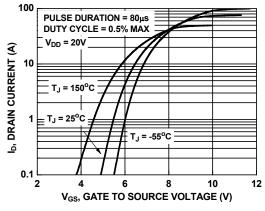


Figure 6. Transfer Characteristics

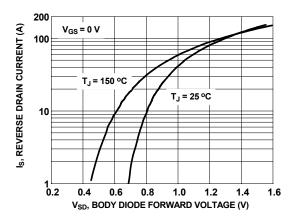


Figure 7. Forward Diode Characteristics

# **Typical Characteristics**

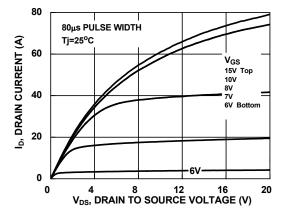


Figure 8. Saturation Characteristics

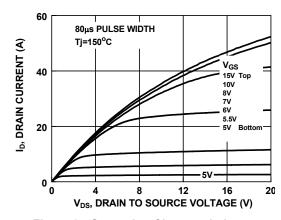


Figure 9. Saturation Characteristics

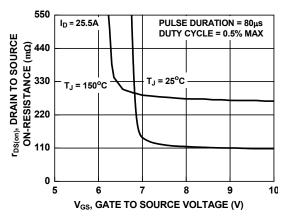


Figure 10. R<sub>DSON</sub> vs. Gate Voltage

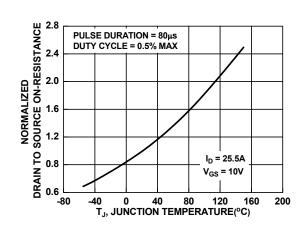


Figure 11. Normalized R<sub>DSON</sub> vs. Junction Temperature

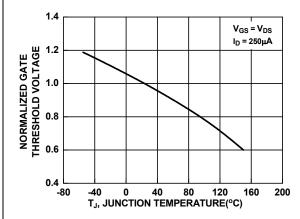


Figure 12. Normalized Gate Threshold Voltage vs. Temperature

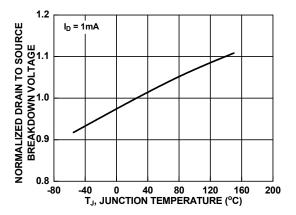


Figure 13. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

# **Typical Characteristics**

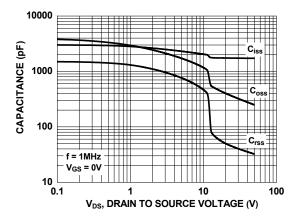


Figure 14. Capacitance vs. Drain to Source Voltage

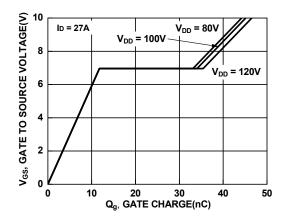


Figure 15. Gate Charge vs. Gate to Source Voltage





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